L Number	Hits		DB	Time stamp
15	41178	gate and (capacitor or capacitance or	USPAT;	2003/08/20 23:03
		capacitive\$2) and (insulat\$4 or	US-PGPUB;	
		dielectric\$3) and ((semiconduct\$3 near2	EPO; JPO	
		island) or transistor or MOSFET\$1 or FET\$1)		
16	47885	gate and (capacitor or capacitance or	USPAT;	2003/08/20 23:03
10	47005	capacitive\$2) and (insulat\$4 or	US-PGPUB;	2003/00/20 23.03
		dielectric\$3) and ((semiconduct\$3 near2	EPO; JPO	
		island) or transistor\$1 or MOSFET\$1 or	220, 020	
		FET\$1 or JFET\$1)		
17	39044	gate and (capacitor or capacitance or	USPAT;	2003/08/20 23:03
		capacitive\$2) and (insulat\$4 or	US-PGPUB;	
		dielectric\$3) and ((semiconduct\$3 near2	EPO; JPO	
		island\$1) or transistor\$1 or MOSFET\$1 or		
		FET\$1 or JFET\$1)		/ /
18	24880	(313/\$7.ccls. or 250/\$7.ccls. or	USPAT;	2003/08/20 23:05
		257/\$7.ccls. or 315/\$7.ccls.) and (gate	US-PGPUB;	
		and (capacitor or capacitance or	EPO; JPO	
		capacitive \$2) and (insulat \$4 or dielectric \$3) and ((semiconduct \$3 near 2		
		island) or transistor\$1 or MOSFET\$1 or		
		FET\$1 or JFET\$1))		
19	2757	((light\$4 adj2 emit\$5) or EL or OLED or	USPAT;	2003/08/20 23:07
	2131	electroluminescen\$4 or luminescen\$4) and	US-PGPUB;	
		((313/\$7.ccls. or 250/\$7.ccls. or	EPO; JPO	
		257/\$7.ccls. or 315/\$7.ccls.) and (gate		
		and (capacitor or capacitance or		
		capacitive\$2) and (insulat\$4 or		
		dielectric\$3) and ((semiconduct\$3 near2		
		island) or transistor\$1 or MOSFET\$1 or		
	1050	FET\$1 or JFET\$1)))		0000/00/00 00 07
20	1958	((light\$4 adj2 emit\$5) or EL or OLED or electroluminescen\$4 or luminescen\$4) and	USPAT; EPO; JPO	2003/08/20 23:07
		((313/\$7.ccls. or 250/\$7.ccls. or	EPO; JPO	
		257/\$7.ccls. or 315/\$7.ccls.) and (gate		
		and (capacitor or capacitance or		
		capacitive\$2) and (insulat\$4 or		
		dielectric\$3) and ((semiconduct\$3 near2		
		island) or transistor\$1 or MOSFET\$1 or		
		FET\$1 or JFET\$1)))		
21	557	1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	USPAT;	2003/08/20 23:07
		adj2 emit\$5) or EL or OLED or	US-PGPUB;	
		electroluminescen\$4 or luminescen\$4) and	EPO; JPO	
		((313/\$7.ccls. or 250/\$7.ccls. or		
		257/\$7.ccls. or 315/\$7.ccls.) and (gate and (capacitor or capacitance or		
		capacitive\$2) and (insulat\$4 or		
		dielectric\$3) and ((semiconduct\$3 near2		
		island) or transistor\$1 or MOSFET\$1 or		
		FET\$1 or JFET\$1))))		
22	163	cathode and anode and (channel\$1 and	USPAT;	2003/08/20 23:08
		(impurit\$3) and (((light\$4 adj2 emit\$5) or	US-PGPUB;	
		EL or OLED or electroluminescen\$4 or	EPO; JPO	
		luminescen\$4) and ((313/\$7.ccls. or		
		250/\$7.ccls. or 257/\$7.ccls. or		
		315/\$7.ccls.) and (gate and (capacitor or		
		capacitance or capacitive\$2) and		
j		(insulat\$4 or dielectric\$3) and		
		((semiconduct\$3 near2 island) or transistor\$1 or MOSFET\$1 or FET\$1 or		
		JFET\$1)))))		
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L Number	Hits	Search Text	DB	Time stamp
15	41178	gate and (capacitor or capacitance or	USPAT;	2003/08/20 23:03
		capacitive\$2) and (insulat\$4 or	US-PGPUB;	
		dielectric\$3) and ((semiconduct\$3 near2	EPO; JPO	
		island) or transistor or MOSFET\$1 or		
16	47885	FET\$1)	USPAT;	2003/08/20 23:03
16	4/885	gate and (capacitor or capacitance or capacitive \$2) and (insulat \$4 or	US-PGPUB;	2003/08/20 23:03
		dielectric\$3) and ((semiconduct\$3 near2	EPO; JPO	
		island) or transistor\$1 or MOSFET\$1 or	220, 020	
		FET\$1 or JFET\$1)		
17	39044	gate and (capacitor or capacitance or	USPAT;	2003/08/20 23:03
		capacitive\$2) and (insulat\$4 or	US-PGPUB;	
		dielectric\$3) and ((semiconduct\$3 near2	EPO; JPO	
		island\$1) or transistor\$1 or MOSFET\$1 or		
18	24880	FET\$1 or JFET\$1) (313/\$7.ccls. or 250/\$7.ccls. or	USPAT;	2003/08/20 23:05
10	24000	257/\$7.ccls. or 315/\$7.ccls.) and (gate	US-PGPUB;	2003/08/20 23:03
		and (capacitor or capacitance or	EPO; JPO	
		capacitive\$2) and (insulat\$4 or	210, 010	
		dielectric\$3) and ((semiconduct\$3 near2		
		island) or transistor\$1 or MOSFET\$1 or		
		FET\$1 or JFET\$1))		
19	2757		USPAT;	2003/08/20 23:07
		electroluminescen\$4 or luminescen\$4) and	US-PGPUB;	
		((313/\$7.ccls. or 250/\$7.ccls. or 257/\$7.ccls. or 315/\$7.ccls.) and (gate	EPO; JPO	
		and (capacitor or capacitance or		
		capacitive\$2) and (insulat\$4 or		
		dielectric\$3) and ((semiconduct\$3 near2		
		island) or transistor\$1 or MOSFET\$1 or		
		FET\$1 or JFET\$1)))		
20	1958		USPAT;	2003/08/20 23:09
		electroluminescen\$4 or luminescen\$4) and	EPO; JPO	
		((313/\$7.ccls. or 250/\$7.ccls. or 257/\$7.ccls. or 315/\$7.ccls.) and (gate		
		and (capacitor or capacitance or		
		capacitive\$2) and (insulat\$4 or		
		dielectric\$3) and ((semiconduct\$3 near2		
		island) or transistor\$1 or MOSFET\$1 or		
		FET\$1 or JFET\$1)))		
21	557		USPAT;	2003/08/20 23:10
		adj2 emit\$5) or EL or OLED or	US-PGPUB;	
		electroluminescen\$4 or luminescen\$4) and ((313/\$7.ccls. or 250/\$7.ccls. or	EPO; JPO	
		257/\$7.ccls. or 315/\$7.ccls.) and (gate		
		and (capacitor or capacitance or		
		capacitive\$2) and (insulat\$4 or		
		dielectric\$3) and ((semiconduct\$3 near2		
		island) or transistor\$1 or MOSFET\$1 or		
	1.00	FET\$1 or JFET\$1))))	HCD2m.	2002/00/20 22 22
22	163	· · · · · · · · · · · · · · · · · · ·	USPAT; US-PGPUB;	2003/08/20 23:10
		(impurit\$3) and (((light\$4 adj2 emit\$5) or EL or OLED or electroluminescen\$4 or	EPO; JPO	
		luminescen\$4) and ((313/\$7.ccls. or	1210, 010	
		250/\$7.ccls. or 257/\$7.ccls. or		
		315/\$7.ccls.) and (gate and (capacitor or		
		capacitance or capacitive\$2) and		
		(insulat\$4 or dielectric\$3) and	1	
		((semiconduct\$3 near2 island) or		
		transistor\$1 or MOSFET\$1 or FET\$1 or JFET\$1))))		
23	2050		USPAT;	2003/08/20 23:09
	2000	electroluminescen\$4 or luminescen\$4 or	EPO; JPO	=300,00,20 23.03
		luminous) and ((313/\$7.ccls. or		
		250/\$7.ccls. or 257/\$7.ccls. or		
		315/\$7.ccls.) and (gate and (capacitor or		
		capacitance or capacitive\$2) and		
		(insulat\$4 or dielectric\$3) and		
		((semiconduct\$3 near2 island) or		
		transistor\$1 or MOSFET\$1 or FET\$1 or JFET\$1)))		
		Orbivill	I	L

24	163	channel\$1 and (impurit\$3) and (cathode and	USPAT;	2003/08/20 23:10
		anode and (channel\$1 and (impurit\$3) and	US-PGPUB;	2555,55,25 25.25
		(((light\$4 adj2 emit\$5) or EL or OLED or	EPO; JPO	
		electroluminescen\$4 or luminescen\$4) and		
		((313/\$7.ccls. or 250/\$7.ccls. or		
		257/\$7.ccls. or 315/\$7.ccls.) and (gate		
		and (capacitor or capacitance or		
		capacitive\$2) and (insulat\$4 or		
		dielectric\$3) and ((semiconduct\$3 near2		
		island) or transistor\$1 or MOSFET\$1 or		
		FET\$1 or JFET\$1))))))		
25	525	channel\$1 and (impurit\$3) and (((light\$4	USPAT;	2003/08/20 23:10
		adj2 emit\$5) or EL or OLED or	US-PGPUB;	
		electroluminescen\$4 or luminescen\$4 or	EPO; JPO	
		luminous) and ((313/\$7.ccls. or		
		250/\$7.ccls. or 257/\$7.ccls. or		
		315/\$7.ccls.) and (gate and (capacitor or		
		capacitance or capacitive\$2) and		
		(insulat\$4 or dielectric\$3) and		
		((semiconduct\$3 near2 island) or		
		transistor\$1 or MOSFET\$1 or FET\$1 or		
		JFET\$1))))		
26	156	, , , , , , , , , , , , , , , , , , , ,	USPAT;	2003/08/20 23:10
		(impurit\$3) and (((light\$4 adj2 emit\$5) or	US-PGPUB;	
		EL or OLED or electroluminescen\$4 or	EPO; JPO	
		luminescen\$4 or luminous) and		
		((313/\$7.ccls. or 250/\$7.ccls. or		
		257/\$7.ccls. or 315/\$7.ccls.) and (gate		
		and (capacitor or capacitance or		
		capacitive\$2) and (insulat\$4 or		
		dielectric\$3) and ((semiconduct\$3 near2   island) or transistor\$1 or MOSFET\$1 or		
	1	FET\$1 or JFET\$1)))))	ł	